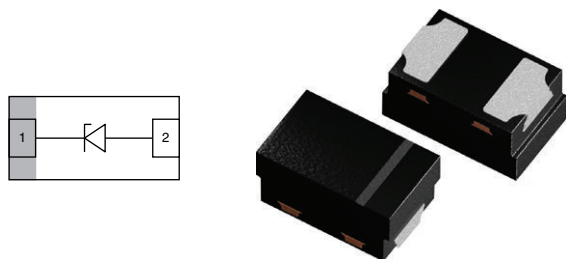


Single-Line Unidirectional ESD-Protection Diode in DFN1006-2A



MARKING (example only)



Bar = pin 1 marking

X = date code

YY = type code (see table below)

LINKS TO ADDITIONAL RESOURCES



FEATURES

- Compact DFN1006-2A package
- Low package height < 0.5 mm
- 1-line unidirectional ESD-protection
- AEC-Q101 qualified available
- Working range 14 V; 28 V
- ESD immunity acc. IEC 61000-4-2
±15 kV to ±30 kV contact discharge
±15 kV to ±30 kV air discharge
- Lead plating: Sn (e3)
- Soldering can be checked by standard vision inspection
- AOI = Automated Optical Inspection
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912



Soldering Recommendations for DFN Packages:

please see Application Note: www.vishay.com/doc?86198

ORDERING INFORMATION

PART NUMBER (EXAMPLE)	AEC-Q101 QUALIFIED	ENVIRONMENTAL AND QUALITY CODE			ORDERING CODE (EXAMPLE)
		RoHS COMPLIANT + LEAD (Pb)-FREE TERMINATIONS	TIN PLATED	10K PER 7" REEL (8 mm TAPE)	
		GREEN		MOQ = 10K/BOX	
VMMBZ16C1HD1	-	G	3	-08	VMMBZ16C1HD1-G3-08
VMMBZ16C1HD1	H	G	3	-08	VMMBZ16C1HD1HG3-08

PACKAGE DATA

DEVICE NAME	PACKAGE NAME	TYPE CODE	WEIGHT	MOLDING COMPOUND FLAMMABILITY RATING	MOISTURE SENSITIVITY LEVEL	SOLDERING CONDITIONS
VMMBZ16C1HD1	DFN1006-2A	2X	0.83 mg	UL 94 V-0	MSL level 1 (according J-STD-020)	Peak temperature max. 260 °C
VMMBZ33C1HD1	DFN1006-2A	2L	0.83 mg	UL 94 V-0	MSL level 1 (according J-STD-020)	Peak temperature max. 260 °C

**ABSOLUTE MAXIMUM RATINGS** VMMBZ16C1HD1(T_{amb} = 25 °C, unless otherwise specified)

PARAMETER	TEST CONDITIONS	SYMBOL	VALUE	UNIT
Peak pulse current	Acc. IEC 61000-4-5, 8/20 µs/single shot	I _{PPM}	4	A
Peak pulse power	Acc. IEC 61000-4-5, 8/20 µs/single shot ⁽¹⁾	P _{PP}	108	W
Peak pulse current	t _p = 10/1000 µs ⁽¹⁾	I _{PPM}	0.7	A
Peak pulse power	t _p = 10/1000 µs ⁽¹⁾	P _{PP}	16	W
ESD immunity	Contact discharge acc. IEC 61000-4-2; 10 pulses ⁽¹⁾	V _{ESD}	30	kV
	Air discharge acc. IEC 61000-4-2; 10 pulses ⁽¹⁾		30	kV
Operating temperature	Junction temperature	T _J	-55 to +150	°C
Storage temperature		T _{stg}	-55 to +150	°C

Note⁽¹⁾ Guaranteed by design; tested during device characterization**ABSOLUTE MAXIMUM RATINGS** VMMBZ33C1HD1(T_{amb} = 25 °C, unless otherwise specified)

PARAMETER	TEST CONDITIONS	SYMBOL	VALUE	UNIT
Peak pulse current	Acc. IEC 61000-4-5, 8/20 µs/single shot	I _{PPM}	1.7	A
Peak pulse power	Acc. IEC 61000-4-5, 8/20 µs/single shot ⁽¹⁾	P _{PP}	100	W
Peak pulse current	t _p = 10/1000 µs ⁽¹⁾	I _{PPM}	0.3	A
Peak pulse power	t _p = 10/1000 µs ⁽¹⁾	P _{PP}	15	W
ESD immunity	Contact discharge acc. IEC 61000-4-2; 10 pulses ⁽¹⁾	V _{ESD}	15	kV
	Air discharge acc. IEC 61000-4-2; 10 pulses ⁽¹⁾		15	kV
Operating temperature	Junction temperature	T _J	-55 to +150	°C
Storage temperature		T _{stg}	-55 to +150	°C

Note⁽¹⁾ Guaranteed by design; tested during device characterization**ELECTRICAL CHARACTERISTICS** VMMBZ16C1HD1(T_{amb} = 25 °C, unless otherwise specified)

PARAMETER	TEST CONDITIONS / REMARKS	SYMBOL	MIN.	TYP.	MAX.	UNIT
Protection paths	Number of lines which can be protected	N _{channel}	-	-	1	lines
Reverse stand off voltage	Max. reverse working voltage	V _{RWM}	-	-	14	V
Reverse voltage	At I _R = 0.01 µA	V _R	14	-	-	V
Reverse current	At V _R = 14 V	I _R	-	< 0.001	0.01	µA
	At V _R = 14 V; T _J = 150 °C ⁽¹⁾		-	0.06	10	µA
Reverse breakdown voltage	At I _R = 1 mA	V _{BR}	15.2	16	16.8	V
	At I _R = 1 mA; T _J = -40 °C to +150 °C ⁽¹⁾		14.3	-	19.0	V
Reverse clamping voltage	At I _{PP} = I _{PPM} = 4 A, t _p = 8/20 µs	V _C	19	23	27	V
	t _p = 100 ns (TLP); I _{TLP} = 16 A ⁽¹⁾	V _{C_TLP}	-	24	-	V
Dynamic resistance	t _p = 100 ns (TLP) ⁽¹⁾	r _{dyn}	-	0.48	-	Ω
Capacitance	At V _R = 0 V; f = 1 MHz	C _D	24.6	29	33.4	pF

Note⁽¹⁾ Guaranteed by design; tested during device characterization

**ELECTRICAL CHARACTERISTICS** VMMBZ33C1HD1(T_{amb} = 25 °C, unless otherwise specified)

PARAMETER	TEST CONDITIONS / REMARKS	SYMBOL	MIN.	TYP.	MAX.	UNIT
Protection paths	Number of lines which can be protected	N _{channel}	-	-	1	lines
Reverse stand off voltage	Max. reverse working voltage	V _{RWM}	-	-	28	V
Reverse voltage	At I _R = 0.01 µA	V _R	28	-	-	V
Reverse current	At V _R = 28 V	I _R	-	< 0.001	0.01	µA
	At V _R = 28 V; T _J = 150 °C ⁽¹⁾		-	0.1	10	µA
Reverse breakdown voltage	At I _R = 1 mA	V _{BR}	31.3	33	34.7	V
	At I _R = 1 mA; T _J = -40 °C to +150 °C ⁽¹⁾		29	-	39	V
Reverse clamping voltage	At I _{PP} = I _{PPM} = 1.7 A, t _p = 8/20 µs	V _C	40	49	59	V
	t _p = 100 ns (TLP); I _{TLP} = 16 A ⁽¹⁾	V _{C,TLP}	-	85	-	V
Dynamic resistance	t _p = 100 ns (TLP) ⁽¹⁾	r _{dyn}	-	0.34	-	Ω
Capacitance	At V _R = 0 V; f = 1 MHz	C _D	13.6	16.1	18.6	pF

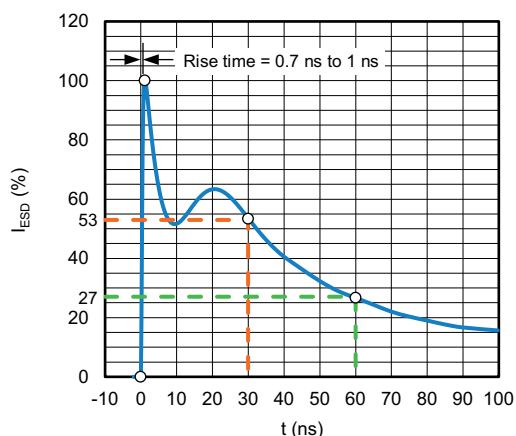
Note⁽¹⁾ Guaranteed by design; tested during device characterization**TYPICAL CHARACTERISTICS** (T_{amb} = 25 °C, unless otherwise specified)

Fig. 1 - ESD Discharge Current Wave Form According to IEC 61000-4-2 (330 Ω / 150 pF)

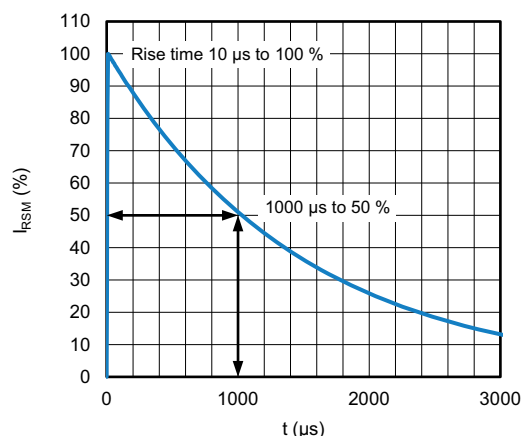


Fig. 3 - 10/1000 µs Peak Pulse Current Wave Form

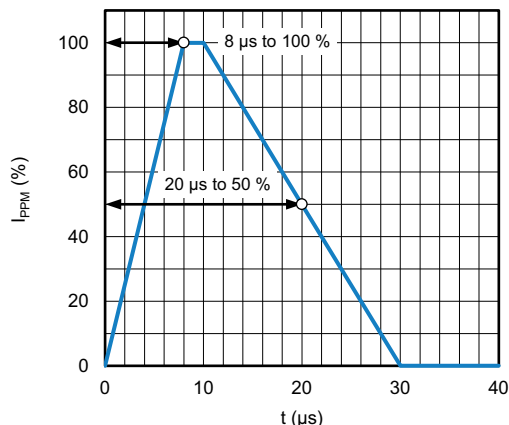


Fig. 2 - 8/20 µs Peak Pulse Current Wave Form According to IEC 61000-4-5

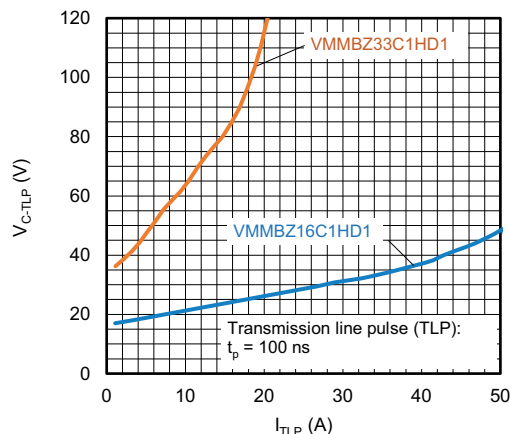


Fig. 4 - Typical Clamping Voltage vs. Peak Pulse Current

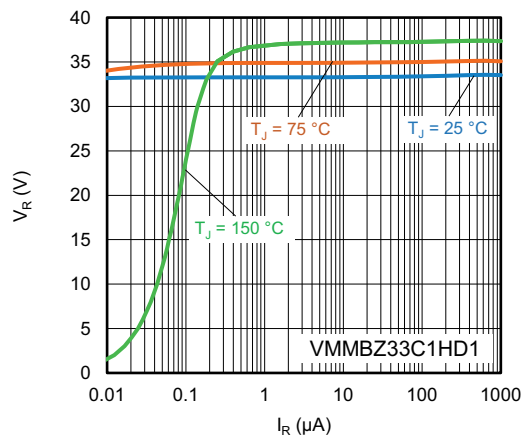


Fig. 5 - Typical Reverse Voltage vs. Reverse Current

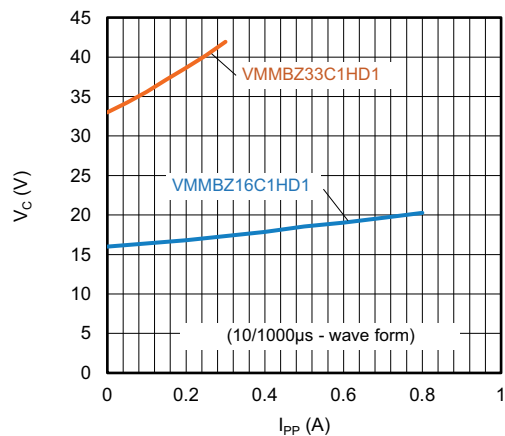


Fig. 8 - Typical Peak Clamping Voltage vs. Peak Pulse Current

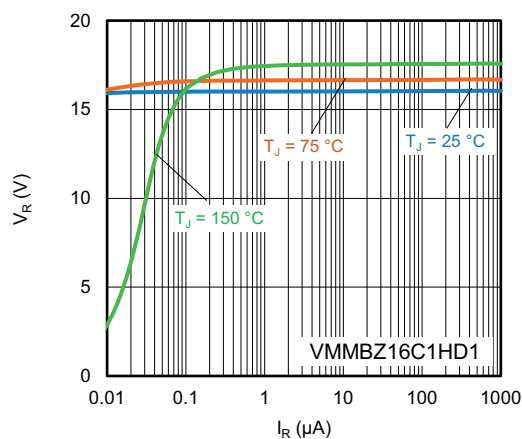


Fig. 6 - Typical Reverse Voltage vs. Reverse Current

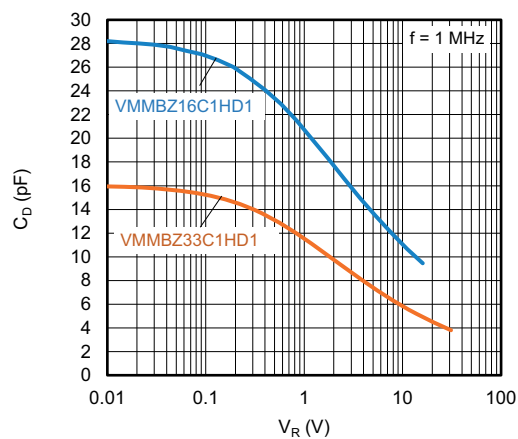


Fig. 9 - Typical Capacitance vs. Reverse Voltage

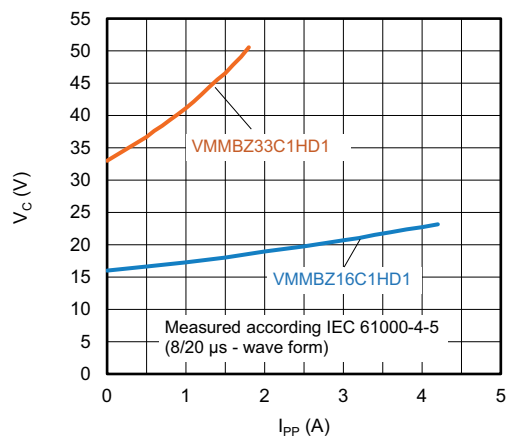
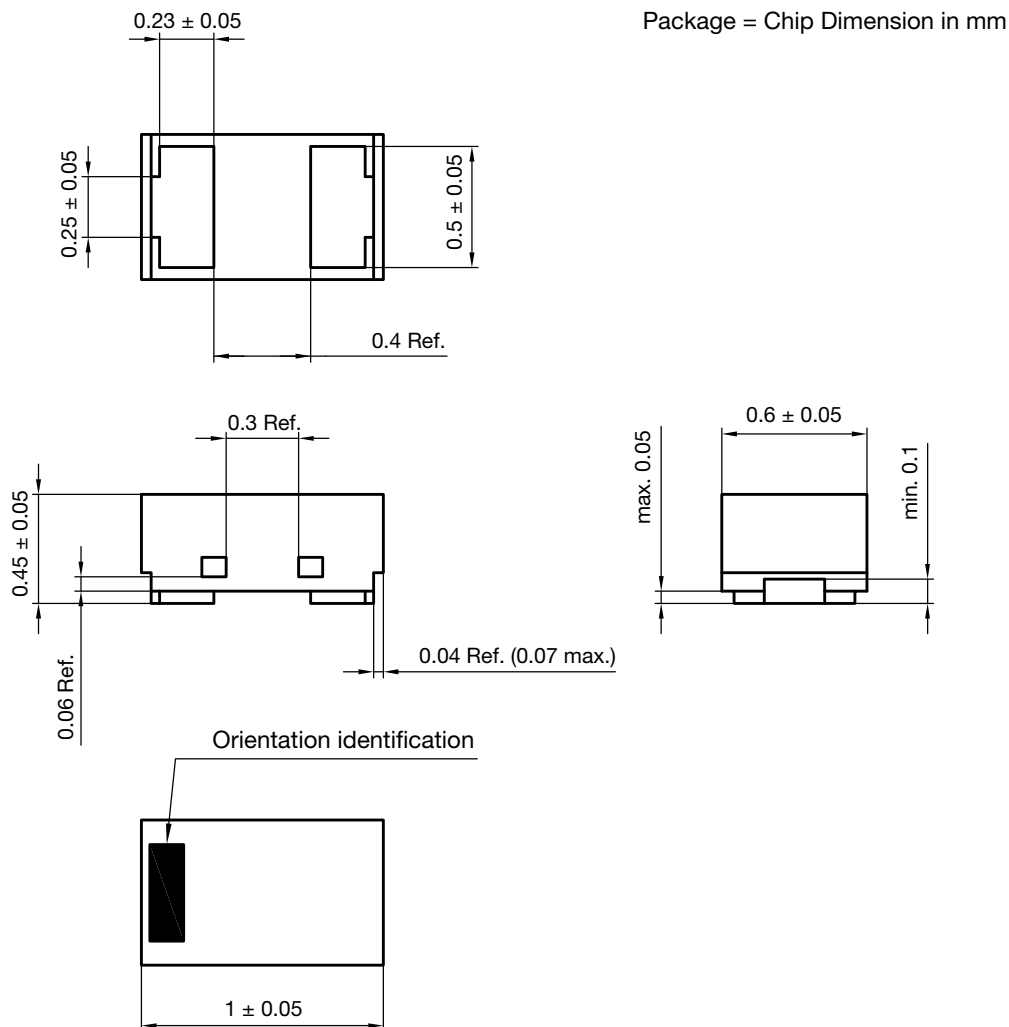


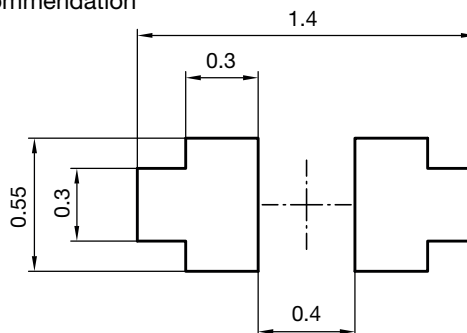
Fig. 7 - Typical Peak Clamping Voltage vs. Peak Pulse Current



PACKAGE DIMENSIONS in millimeters (Inches): DFN1006-2A



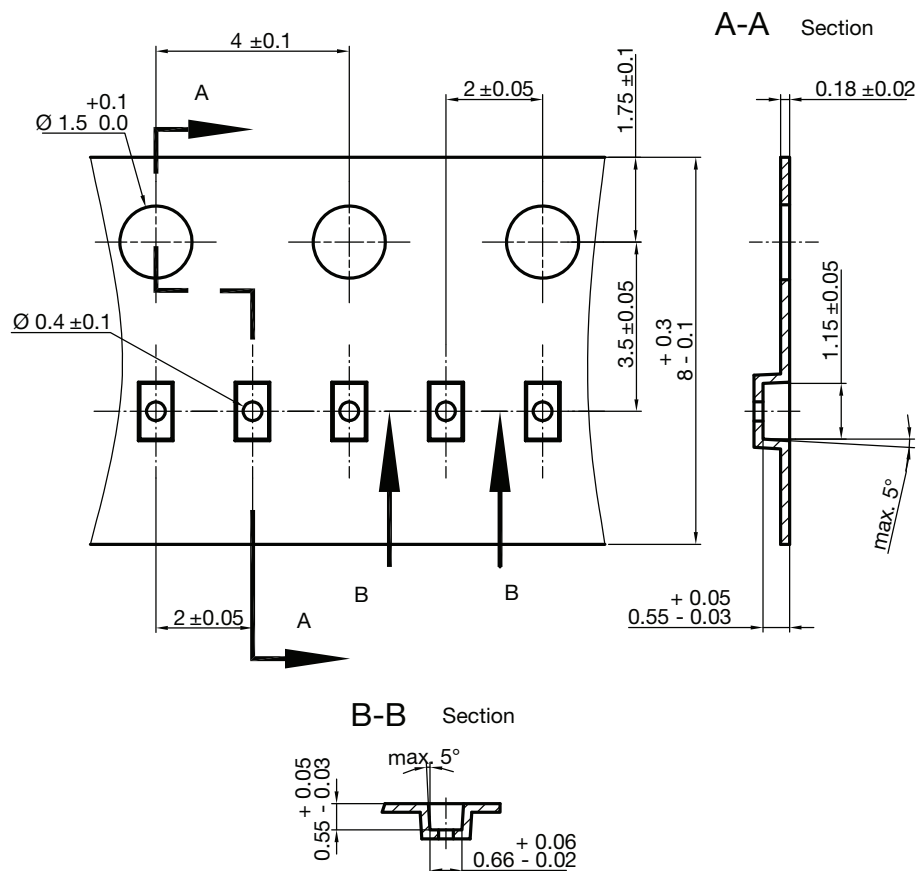
Footprint recommendation



Document no.: S8-V-3906.04-059 (4)
Created - Date: 11-Jul-2018
Rev.5 - Date: 17-Sep-2021

23191

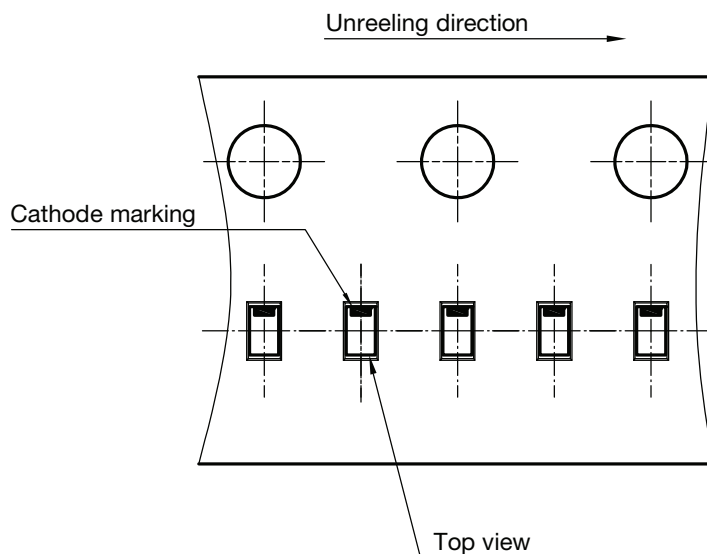
CARRIER TAPE DFN1006-2A



S8-V-3906.04-063 (4)
created 28.10.2019

surface resistance: $10^5 - 10^{11} \frac{\text{OHMS}}{\text{SQ}}$
Cumulative tolerances of 10 sprocket holes is $\pm 0.2 \text{ mm}$

ORIENTATION IN CARRIER TAPE DFN1006-2A



S8-V-3906.04-064 (4)
created 28.10.2019



Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Hyperlinks included in this datasheet may direct users to third-party websites. These links are provided as a convenience and for informational purposes only. Inclusion of these hyperlinks does not constitute an endorsement or an approval by Vishay of any of the products, services or opinions of the corporation, organization or individual associated with the third-party website. Vishay disclaims any and all liability and bears no responsibility for the accuracy, legality or content of the third-party website or for that of subsequent links.

Vishay products are not designed for use in life-saving or life-sustaining applications or any application in which the failure of the Vishay product could result in personal injury or death unless specifically qualified in writing by Vishay. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.